## AMENDMENTS TO THE CLAIMS:

This listing of claims will replace all prior versions, and listings, of claims in the application:

## LISTING OF CLAIMS:

1. (previously presented) A slurry for chemical mechanical polishing, which comprises a silica polishing material, an oxidizing agent, a benzotriazole-based compound, a diketone and water, and

wherein said diketone is at least one type of a compound selected from the group consisting of 1, 2-diketones, 1, 3-diketones and 1, 4-diketones, and

wherein a content weight ratio of said diketone to said benzotriazole-based compound (diketone/benzotriazole-based compound) is not less than 0.05 but not greater than 50.

## 2-3. (cancelled)

- 4. (original) A slurry for chemical mechanical polishing according to Claim 1, wherein a value of a pH is in a range of 1 to 7.
- 5. (original) A slurry for chemical mechanical polishing according to Claim 1, wherein said silica polishing material is colloidal silica.
- 6. (currently amended) The slurry for chemical mechanical polishing according to claim 1, wherein a content weight ratio of said diketone to said benzotriazole-based

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compound (diketone/benzotriazole-based compound) is not less than 0.05 0.1 but not greater than 50 10.

- 7. (new) The slurry for chemical mechanical polishing according to claim 1, wherein the content of the silica polishing material is not less than 1 wt%.
- 8. (new) The slurry for chemical mechanical polishing according to claim 1, wherein the content of the silica polishing material is not less than 1 wt% but not greater than 10 wt%.
- 9. (new) The slurry for chemical mechanical polishing according to claim 1, wherein the content of the benzotriazole-based compound is not less than 0.001 wt% but not greater than 0.5 wt%.
- 10. (new) The slurry for chemical mechanical polishing according to claim 1, wherein the content of the diketone is not less than 0.001 wt% but not greater than 5 wt%.